

High-reliability discrete products and engineering services since 1977

FJT1100, FJT1101

ULTRA LOW LEAKAGE DIODES

FEATURES

- Available as "HR" (high reliability) screened per MIL-PRF-19500, JANTX level. Add "HR" suffix to base part number.
- Available as non-RoHS (Sn/Pb plating), standard, and as RoHS by adding "-PBF" suffix.

MAXIMUM RATINGS

Characteristics	Value
Storage temperature range	-55° to +200°C
Maximum junction operating temperature	+175°C
Lead temperature	+260°C
Power dissipation	
Maximum total power dissipation at 25°C ambient	250 mW
Linear power derating factor (from 25°C)	1.67 mW/°C
Working inverse voltage	
FJT1100	25V
FJT1101	15V
Continuous forward current	150 mA

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise specified)

Symbol	Characteristi	Min	Max	Units	Test Conditions	
BV	Drookdown voltogo	FJT1100	30		V	I - F 0A
ΒV	Breakdown voltage	FJT1101	20		V	I _R = 5.0μA
I _R	Reverse current	FJT1100		1.0		V _R = 5.0V
				10	pA	V _R = 15V
		FJT1101		5.0	рΑ	$V_{R} = 5.0V$
				15		V _R = 15V
V _F	Forward voltage	FJT1100		1.05	V	I _F = 50mA
		FJT1101		1.10		
С	Capacitance	FJT1100		1.5	pF	V _R = 0, f = 1MHz
		FJT1101		1.8		



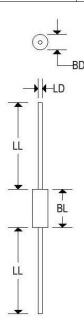
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MECHANICAL CHARACTERISTICS

Case	DO-35
Marking	Body painted, alpha-numeric
Polarity	Cathode band



	DO-35						
	Inc	hes	Millimeters				
	Min	Max	Min	Max			
BD	0.055	0.090	1.400	2.290			
BL	0.120	0.200	3.050	5.080			
LD	0.018	0.022	0.460	0.560			
LL	1.000	1.500	25,400	38,100			